NSN 5961-01-066-8352

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View Online at https://aerobasegroup.com/nsn/5961-01-066-8352 **Inclosure Material:** Metal **Overall Length:** 0.810 inches **Overall Height:** 0.187 inches **Overall Width:** 0.255 inches **Internal Configuration:** Junction contact **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 40.0 collector to base voltage/static/emitter open and 40.0 collector-to-emitter, resistance between base and emitter and 3.0 emitter to base voltage, static, collector open **Transfer Ratio:** 120.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 4 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: